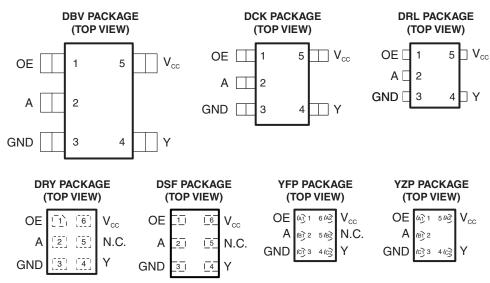
SCES596E-JULY 2004-REVISED SEPTEMBER 2009

LOW-POWER SINGLE BUS BUFFER GATE WITH 3-STATE OUTPUT

FEATURES

- Available in the Texas Instruments NanoStar™ Package
- Low Static-Power Consumption (I_{CC} = 0.9 μA Max)
- Low Dynamic-Power Consumption (C_{pd} = 4 pF Typ at 3.3 V)
- Low Input Capacitance (C_i = 1.5 pF Typ)
- Low Noise Overshoot and Undershoot <10% of V_{CC}
- Input-Disable Feature Allows Floating Input Conditions
- I_{off} Supports Partial-Power-Down Mode Operation

- Input Hysteresis Allows Slow Input Transition and Better Switching Noise Immunity at Input
- Wide Operating V_{CC} Range of 0.8 V to 3.6 V
- Optimized for 3.3-V Operation
- 3.6-V I/O Tolerant to Support Mixed-Mode Signal Operation
- $t_{nd} = 4.6 \text{ ns Max at } 3.3 \text{ V}$
- Suitable for Point-to-Point Applications
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II
- ESD Performance Tested Per JESD 22-
 - 2000-V Human-Body Model (A114-B, Class II)
 - 1000-V Charged-Device Model (C101)



N.C. - No internal connection.

See mechanical drawings for dimensions.

DESCRIPTION/ORDERING INFORMATION

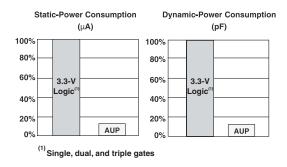
The AUP family is TI's premier solution to the industry's low-power needs in battery-powered portable applications. This family ensures a very low static and dynamic power consumption across the entire V_{CC} range of 0.8 V to 3.6 V, resulting in an increased battery life. This product also maintains excellent signal integrity (see Figure 1 and Figure 2).

M

Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

NanoStar is a trademark of Texas Instruments.





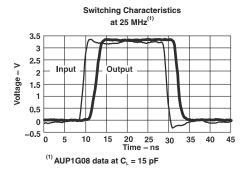


Figure 1. AUP - The Lowest-Power Family

Figure 2. Excellent Signal Integrity

This bus buffer gate is a single line driver with a 3-state output. The output is disabled when the output-enable (OE) input is low. This device has the input-disable feature, which allows floating input signals.

To ensure the high-impedance state during power up or power down, OE should be tied to GND through a pulldown resistor; the minimum value of the resistor is determined by the current-sourcing capability of the driver.

NanoStar™ package technology is a major breakthrough in IC packaging concepts, using the die as the package.

This device is fully specified for partial-power-down applications using I_{off} . The I_{off} circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.

ORDERING INFORMATION(1)

T _A	PACKAGE ⁽²⁾		ORDERABLE PART NUMBER	TOP-SIDE MARKING ⁽³⁾			
	NanoStar™ – WCSP (DSBGA) 0.23-mm Large Bump – YFP	Reel of 3000	SN74AUP1G126YFPR	HN			
	NanoStar™ – WCSP (DSBGA) 0.23-mm Large Bump – YZP (Pb-free)	Reel of 3000	SN74AUP1G126YZPR	HN _			
	QFN – DRY	Reel of 5000	SN74AUP1G126DRYR	PREVIEW			
-40°C to 85°C	μQFN – DSF	Reel of 5000	SN74AUP1G126DSFR	PREVIEW			
	SOT (SOT-23) – DBV	Reel of 3000	SN74AUP1G126DBVR	1106			
	SOT (SOT-23) – DBV	Reel of 250	SN74AUP1G126DBVT	H26_			
	SOT (SC-70) – DCK	Reel of 3000	SN74AUP1G126DCKR	- HN			
	301 (3C-70) - DCK	Reel of 250	SN74AUP1G126DCKT	піл_			
	SOT (SOT-553) – DRL	Reel of 4000	SN74AUP1G126DRLR	HN_			

⁽¹⁾ For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI web site at www.ti.com.

(2) Package drawings, thermal data, and symbolization are available at www.ti.com/packaging.

FUNCTION TABLE

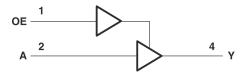
INP	OUTPUT	
OE	Α	Y
Н	Н	Н
Н	L	L
L	X ⁽¹⁾	Z

(1) Floating inputs allowed

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⁽³⁾ DBV/DCK/DRL: The actual top-side marking has one additional character that designates the wafer fab/assembly site. YZP/YZT: The actual top-side marking has three preceding characters to denote year, month, and sequence code, and one following character to designate the wafer fab/assembly site. Pin 1 identifier indicates solder-bump composition (1 = SnPb, • = Pb-free).

LOGIC DIAGRAM (POSITIVE LOGIC)





ABSOLUTE MAXIMUM RATINGS(1)

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
V_{CC}	Supply voltage range		-0.5	4.6	V
V_{I}	Input voltage range ⁽²⁾		-0.5	4.6	V
Vo	Voltage range applied to any output in the high-impeda	ance or power-off state (2)	-0.5	4.6	V
Vo	Output voltage range in the high or low state ⁽²⁾		-0.5	V _{CC} + 0.5	V
I _{IK}	Input clamp current	V _I < 0		-50	mA
lok	Output clamp current	V _O < 0		-50	mA
Io	Continuous output current		±20	mA	
	Continuous current through V _{CC} or GND			±50	mA
		DBV package		206	
		DCK package		252	
0	Dark and the condition of the condition (3)	DRL package		142	00.004
θ_{JA}	Package thermal impedance (3)	DSF package		TBD	°C/W
		DRY package		234	
		YFP/YZP/YZT package		132	
T _{stg}	Storage temperature range		-65	150	°C

⁽¹⁾ Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

⁽²⁾ The input negative-voltage and output voltage ratings may be exceeded if the input and output current ratings are observed.

⁽³⁾ The package thermal impedance is calculated in accordance with JESD 51-7.

RECOMMENDED OPERATING CONDITIONS⁽¹⁾

			MIN	MAX	UNIT
V _{CC}	Supply voltage		0.8	3.6	V
		V _{CC} = 0.8 V	V _{CC}	3.6	
V	High level input valtage	V _{CC} = 1.1 V to 1.95 V	0.65 × V _{CC}	3.6	V
V_{IH}	High-level input voltage	$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$	1.6	3.6	V
		V _{CC} = 3 V to 3.6 V	2	3.6	
		V _{CC} = 0.8 V		0	
V	Low lovel input voltage	V _{CC} = 1.1 V to 1.95 V	0	0.35 × V _{CC}	V
V_{IL}	Low-level input voltage	$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$	0	0.7	V
		V _{CC} = 3 V to 3.6 V	0	0.9	
V	Output voltage	Active state	0	V_{CC}	V
Vo	output voltage	3-state	0	3.6	V
		V _{CC} = 0.8 V		-20	μΑ
		V _{CC} = 1.1 V		-1.1	
	High level output ourrent	V _{CC} = 1.4 V		-1.7	
I _{OH}	High-level output current	V _{CC} = 1.65 V		-1.9	mA
		V _{CC} = 2.3 V		-3.1	
		$V_{CC} = 3 V$		-4	
		V _{CC} = 0.8 V		20	μΑ
		V _{CC} = 1.1 V		1.1	
	Low-level output current	V _{CC} = 1.4 V		1.7	
l _{OL}	Low-level output current	V _{CC} = 1.65 V		mA	
		V _{CC} = 2.3 V	3.1		
		V _{CC} = 3 V			
Δt/Δν	Input transition rise or fall rate	V _{CC} = 0.8 V to 3.6 V		200	ns/V
T _A	Operating free-air temperature		-40	85	°C

⁽¹⁾ All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow of Floating CMOS Inputs, literature number SCBA004.



ELECTRICAL CHARACTERISTICS

over recommended operating free-air temperature range (unless otherwise noted)

DAF	AMETER	TEST CONDITIONS	V	Т,	_A = 25°C	T _A = -40°C to 85°C	UNIT	
PAR	RAMETER	TEST CONDITIONS	V _{cc}	MIN	TYP MAX	MIN MAX	UNII	
		$I_{OH} = -20 \mu A$	0.8 V to 3.6 V	V _{CC} - 0.1		V _{CC} - 0.1		
		I _{OH} = -1.1 mA	1.1 V	0.75 × V _{CC}	\times V _{CC} 0.7 \times V _{CC}			
		$I_{OH} = -1.7 \text{ mA}$	1.4 V	1.11		1.03		
\		I _{OH} = -1.9 mA	1.65 V	1.32		1.3	V	
V_{OL}		I _{OH} = -2.3 mA	221/	2.05		1.97	V	
		$I_{OH} = -3.1 \text{ mA}$	2.3 V	1.9		1.85		
		$I_{OH} = -2.7 \text{ mA}$	2.1/	2.72		2.67		
		$I_{OH} = -4 \text{ mA}$	3 V	2.6		2.55		
		I _{OL} = 20 μA	0.8 V to 3.6 V		0.1	0.1		
		I _{OL} = 1.1 mA	1.1 V		0.3 × V _{CC}	0.3 × V _{CC}		
V _{OL}		I _{OL} = 1.7 mA	1.4 V		0.31	0.37		
		I _{OL} = 1.9 mA	1.65 V		0.31	0.35	.,	
		I _{OL} = 2.3 mA	0.01/		0.31	0.33	V	
		I _{OL} = 3.1 mA	2.3 V		0.44	0.45		
		I _{OL} = 2.7 mA	0.1/		0.31	0.33		
		I _{OL} = 4 mA	3 V		0.44	0.45		
I _I	A or OE input	V _I = GND to 3.6 V	0 V to 3.6 V		0.1	0.5	μА	
I _{off}		V_I or $V_O = 0$ V to 3.6 V	0 V		0.2	0.6	μА	
ΔI_{off}		V_I or $V_O = 0$ V to 3.6 V	0 V to 0.2 V		0.2	0.6	μΑ	
loz		$V_O = V_{CC}$ or GND	3.6 V			0.5	μА	
I _{CC}		$V_I = GND \text{ or } (V_{CC} \text{ to } 3.6 \text{ V}),$ $OE = GND, I_O = 0$	0.8 V to 3.6 V		0.5	0.9	μА	
	A input	$V_1 = V_{CC} - 0.6 V^{(1)},$	0.01/		40	50		
ΔI_{CC}	OE input $I_0 = 0$		3.3 V		120	μΑ		
All inputs		$V_I = GND \text{ to } 3.6 \text{ V},$ $OE = V_{CC}^{(2)}$	0.8 V to 3.6 V		0	0		
_		V V 0ND	0 V		1.5		_	
Ci		$V_I = V_{CC}$ or GND	3.6 V		1.5		pF	
C _o		$V_O = V_{CC}$ or GND	3.6 V		3		pF	

 $[\]begin{array}{ll} \hbox{(1)} & \hbox{One input at $V_{CC}-0.6$ V, other input at V_{CC} or GND} \\ \hbox{(2)} & \hbox{To show I_{CC} is very low when the input-disable feature is enabled} \end{array}$

SWITCHING CHARACTERISTICS

over recommended operating free-air temperature range, $C_L = 5 \text{ pF}$ (unless otherwise noted) (see Figure 3 and Figure 4)

PARAMETER	FROM	FROM TO (OUTPUT)	V _{cc}	T _A = 25°C			T _A = -40°C to 85°C		UNIT
	(INPUT)	(001701)		MIN	TYP	MAX	MIN	MAX	
			0.8 V		18.1				
			1.2 V ± 0.1 V	4.3	7.4	12.6	2.7	15.3	
4	А	Y	1.5 V ± 0.1 V	3.3	5.2	8.5	1	10.2	
t _{pd}	А	Ť	1.8 V ± 0.15 V	2.6	4.1	6.8	1.3	8.3	ns
			2.5 V ± 0.2 V	2	2.9	4.7	1.1	5.8	
			3.3 V ± 0.3 V	1.7	2.4	3.8	1	4.6	
		DE Y	0.8 V		19.1				
			1.2 V ± 0.1 V	5.1	9.3	15.9	3.6	19.2	20
	OE		1.5 V ± 0.1 V	4.1	6.6	10.5	2.5	12.7	
t _{en}	OE	Ť	1.8 V ± 0.15 V	3.2	5.3	8.7	2.1	10.3	ns
			2.5 V ± 0.2 V	2.5	3.8	6	1.6	7.2	
			3.3 V ± 0.3 V	2.1	3.2	4.9	1.4	5.9	
			0.8 V		12.1				
			1.2 V ± 0.1 V	2.4	4.1	6.9	2.2	7.7	
	OF	Y	1.5 V ± 0.1 V	1.8	2.9	4.5	1.7	5.1	
t _{dis}	OE	Y	1.8 V ± 0.15 V	1	2.9	4.3	1.5	4.7	ns
			2.5 V ± 0.2 V	1	1.8	2.7	1	3.3	
			3.3 V ± 0.3 V	1.2	2.2	3.2	1.1	4	



SWITCHING CHARACTERISTICS

over recommended operating free-air temperature range, $C_L = 10 \text{ pF}$ (unless otherwise noted) (see Figure 3 and Figure 4)

PARAMETER	ARAMETER FROM TO (OUTPUT)	V _{cc}	T _A = 25°C			T _A = -40°C to 85°C		UNIT				
	(INPUT)	(001P01)		MIN	TYP	MAX	MIN	MAX				
			0.8 V		20.5	13.7						
				1.2 V ± 0.1 V	4.6	8.4	9.3	3.6	16.6			
	A == D	Y	1.5 V ± 0.1 V	3.5	5.9	7.5	2.4	11.1				
t _{pd}	A or B	Y	1.8 V ± 0.15 V	3.9	4.7	5.3	1.3	9.1	ns			
			2.5 V ± 0.2 V	2.3	3.4	4.3	1.6	6.4				
			3.3 V ± 0.3 V	2.1	2.8		1.4	5.2				
	05				0.8 V		21.8	16.8				
			1.2 V ± 0.1 V	4.9	10.2	11.2	4.4	20.2				
		OF	05	0.5	0.5	Y	1.5 V ± 0.1 V	3.9	7.3	9.2	3.3	13.5
t _{en}	OE	Y	1.8 V ± 0.15 V	3.4	5.8	6.4	2.7	11	ns			
			2.5 V ± 0.2 V	2.5	4.3	5.4	2.1	7.8				
			3.3 V ± 0.3 V	2.1	3.7		1.9	6.4				
			0.8 V		13							
			1.2 V ± 0.1 V	3.8	6.6	11.7	1.2	14				
	0.5		1.5 V ± 0.1 V	2.2	4.7	7.9	1.3	9.3	ns			
t _{dis}	OE	OE Y	1.8 V ± 0.15 V	2.4	4.4	6.4	2.2	7.5				
			2.5 V ± 0.2 V	1.3	3.1	4.9	1.2	5.4				
1			3.3 V ± 0.3 V	1.9	3.4	5	1.9	5.6				

SWITCHING CHARACTERISTICS

over recommended operating free-air temperature range, $C_L = 15 \ pF$ (unless otherwise noted) (see Figure 3 and Figure 4)

PARAMETER	FROM TO (OUTPUT)			V _{cc}	T _A = 25°C			T _A = -40°C to 85°C		UNIT
			MIN	TYP	MAX	MIN	MAX			
			0.8 V		22.5					
			1.2 V ± 0.1 V	5.8	9.3	15.1	4.3	17.9		
	A D	Y	1.5 V ± 0.1 V	4.4	6.6	10.2	3	12.1		
t _{pd}	A or B	Ť	1.8 V ± 0.15 V	3.5	5.3	8.3	2.3	9.9	ns	
			2.5 V ± 0.2 V	2.7	3.9	5.8	1.9	7		
			3.3 V ± 0.3 V	2.4	3.2	4.7	1.8	5.7		
	OE			0.8 V		25.2				
			1.2 V ± 0.1 V	7	11.3	18.1	5.4	21.4		
		Y	1.5 V ± 0.1 V	5.5	8.1	12.2	4.1	14.5		
t _{en}	OE	Ť	1.8 V ± 0.15 V	4.3	6.5	10.1	3.3	12	ns	
			2.5 V ± 0.2 V	3.4	4.8	7.1	2.6	8.4		
			3.3 V ± 0.3 V	2.9	4.1	5.9	2.3	6.9		
			0.8 V		14					
			1.2 V ± 0.1 V	3.7	5.8	8.2	3.3	11		
	OF	Y	1.5 V ± 0.1 V	5.5	3.9	5.9	2.1	8		
t _{dis}	OE	Y	1.8 V ± 0.15 V	3.3	4.5	6.6	2.9	7.4	ns	
			2.5 V ± 0.2 V	2.3	3.2	4.3	1.8	5.1		
			3.3 V ± 0.3 V	2.4	4.8	6.2	3.1	6.7		



SWITCHING CHARACTERISTICS

over recommended operating free-air temperature range, $C_L = 30 \text{ pF}$ (unless otherwise noted) (see Figure 3 and Figure 4)

PARAMETER	FROM	TO (OUTBUT)	V _{cc}	T	λ = 25°C		T _A = -4 to 85°		UNIT			
	(INPUT)	(OUTPUT)	''	MIN	TYP	MAX	MIN	MAX				
			0.8 V		29							
						1.2 V ± 0.1 V	7.4	12	18.7	6.6	21.4	
4	Λ or D	Y	1.5 V ± 0.1 V	5.7	8.6	12.5	4.9	14.7	20			
t _{pd}	A or B	Ť	1.8 V ± 0.15 V	4.8	6.9	10.1	3.1	12	ns			
			2.5 V ± 0.2 V	3.9	5.1	7.2	3.3	8.7				
			3.3 V ± 0.3 V	3.5	4.8	6	3	7				
						0.8 V		33.4				
			1.2 V ± 0.1 V	8.8	14.1	21.8	7.4	25.5				
	05	Y	1.5 V ± 0.1 V	6.9	10.1	14.6	5.6	17.4				
t _{en}	OE	Y	1.8 V ± 0.15 V	5.6	8.1	12	4.7	14.1	ns			
			2.5 V ± 0.2 V	4.3	6.1	8.5	3.8	10				
			3.3 V ± 0.3 V	3.7	5.2	7.1	3.4	8.3				
			0.8 V		17.7							
			1.2 V ± 0.1 V	5.8	10	16	3.7	16				
	05	Y	1.5 V ± 0.1 V	5.7	7.7	10.9	1	10.7				
t _{dis}	OE	Y	1.8 V ± 0.15 V	4.5	7.7	9.8	4.4	12.5	ns			
			2.5 V ± 0.2 V	3.9	5.6	7.4	3.2	9				
			3.3 V ± 0.3 V	3.3	8.4	10.7	6.6	10.8				

OPERATING CHARACTERISTICS

 $T_A = 25^{\circ}C$

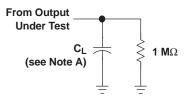
	PARAMETER		TEST CONDITIONS	V _{cc}	TYP	UNIT
				0.8 V	3.8	
				1.2 V ± 0.1 V	3.7	
		Outrotte e ellest	f 40 MH=	1.5 V ±0.1 V	3.7	
	Outputs enabled	f = 10 MHz	1.8 V ± 0.15 V	3.7		
				2.5 V ± 0.2 V	3.9	
				$3.3 \text{ V} \pm 0.3 \text{ V}$	4	
C _{pd}	Power dissipation capacitance			0.8 V	0	pF
	capacitarios			1.2 V ± 0.1 V	0	
				1.5 V ±0.1 V	0	
		Outputs disable	f = 10 MHz	1.8 V ± 0.15 V	0	
				2.5 V ± 0.2 V	0	
				2.5 V ± 0.2 V	0	
				3.3 V ± 0.3 V	0	

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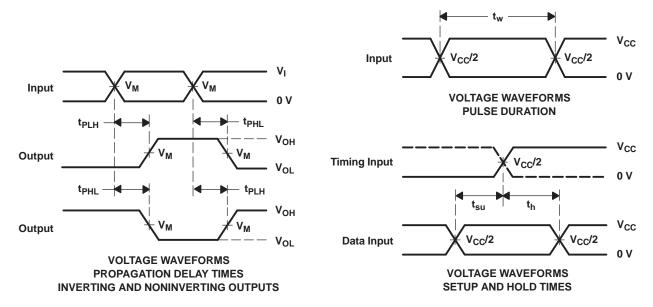
PARAMETER MEASUREMENT INFORMATION

(Propagation Delays, Setup and Hold Times, and Pulse Width)



LOAD CIRCUIT

	V _{CC} = 0.8 V	V _{CC} = 1.2 V ± 0.1 V	V _{CC} = 1.5 V ± 0.1 V	V _{CC} = 1.8 V ± 0.15 V	V_{CC} = 2.5 V \pm 0.2 V	V _{CC} = 3.3 V ± 0.3 V
C _L	5, 10, 15, 30 pF	5, 10, 15, 30 pF	5, 10, 15, 30 pF	5, 10, 15, 30 pF	5, 10, 15, 30 pF	5, 10, 15, 30 pF
V _M	V _{CC} /2	V _{CC} /2	V _{CC} /2	V _{CC} /2	V _{CC} /2	V _{CC} /2
V _I	V _{CC}	V _{CC}	V _{CC}	V _{CC}	V _{CC}	V _{CC}



NOTES: A. C_L includes probe and jig capacitance.

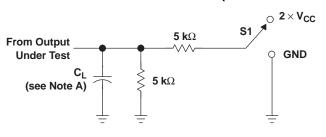
- B. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, $Z_O = 50 \Omega$, $t_r/t_f = 3 \text{ ns}$.
- C. The outputs are measured one at a time, with one transition per measurement.
- D. t_{PLH} and t_{PHL} are the same as t_{pd} .
- E. All parameters and waveforms are not applicable to all devices.

Figure 3. Load Circuit and Voltage Waveforms



PARAMETER MEASUREMENT INFORMATION (continued)

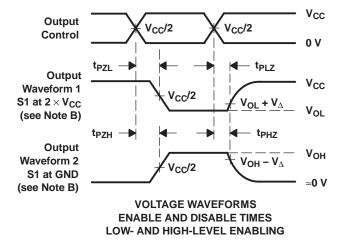
(Enable and Disable Times)



TEST	S1
t _{PLZ} /t _{PZL}	2×V _{CC}
t _{PHZ} /t _{PZH}	GND

LOAD CIRCUIT

	V _{CC} = 0.8 V	V _{CC} = 1.2 V ± 0.1 V	V _{CC} = 1.5 V ± 0.1 V	V _{CC} = 1.8 V ± 0.15 V	V_{CC} = 2.5 V \pm 0.2 V	V _{CC} = 3.3 V ± 0.3 V
C _L	5, 10, 15, 30 pF	5, 10, 15, 30 pF	5, 10, 15, 30 pF	5, 10, 15, 30 pF	5, 10, 15, 30 pF	5, 10, 15, 30 pF
V _M	V _{CC} /2	V _{CC} /2	V _{CC} /2	V _{CC} /2	V _{CC} /2	V _{CC} /2
V _I	V _{CC}	V _{CC}	V _{CC}	V _{CC}	V _{CC}	V _{CC}
V _∆	0.1 V	0.1 V	0.1 V	0.15 V	0.15 V	0.3 V



NOTES: A. C_L includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, $Z_O = 50~\Omega$, $t_r/t_f = 3~ns$.
- D. The outputs are measured one at a time, with one transition per measurement.
- E. t_{PLZ} and t_{PHZ} are the same as t_{dis}.
- F. t_{PZL} and t_{PZH} are the same as t_{en}.
- G. All parameters and waveforms are not applicable to all devices.

Figure 4. Load Circuit and Voltage Waveforms

PACKAGE OPTION ADDENDUM

www.ti.com 5-Oct-2009

PACKAGING INFORMATION

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	e Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp ⁽³⁾
74AUP1G126DBVRE4	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
74AUP1G126DBVRG4	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
74AUP1G126DBVTE4	ACTIVE	SOT-23	DBV	5	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
74AUP1G126DBVTG4	ACTIVE	SOT-23	DBV	5	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
74AUP1G126DCKRE4	ACTIVE	SC70	DCK	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
74AUP1G126DCKRG4	ACTIVE	SC70	DCK	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
74AUP1G126DCKTE4	ACTIVE	SC70	DCK	5	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
74AUP1G126DCKTG4	ACTIVE	SC70	DCK	5	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
74AUP1G126DRLRG4	ACTIVE	SOT	DRL	5	4000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74AUP1G126DBVR	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74AUP1G126DBVT	ACTIVE	SOT-23	DBV	5	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74AUP1G126DCKR	ACTIVE	SC70	DCK	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74AUP1G126DCKT	ACTIVE	SC70	DCK	5	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74AUP1G126DRLR	ACTIVE	SOT	DRL	5	4000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74AUP1G126YFPR	ACTIVE	DSBGA	YFP	6	3000	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM
SN74AUP1G126YZPR	ACTIVE	DSBGA	YZP	5	3000	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

⁽²⁾ Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.



PACKAGE OPTION ADDENDUM

www.ti.com 5-Oct-2009

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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PACKAGE MATERIALS INFORMATION

www.ti.com 1-Oct-2009

TAPE AND REEL INFORMATION





		Dimension designed to accommodate the component width
		Dimension designed to accommodate the component length
	K0	Dimension designed to accommodate the component thickness
		Overall width of the carrier tape
Γ	P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE

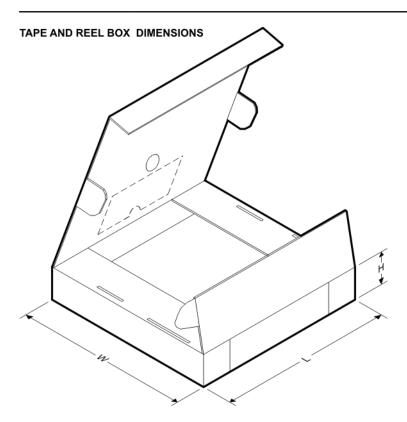


*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74AUP1G126DBVR	SOT-23	DBV	5	3000	180.0	9.2	3.23	3.17	1.37	4.0	8.0	Q3
SN74AUP1G126DBVT	SOT-23	DBV	5	250	180.0	9.2	3.23	3.17	1.37	4.0	8.0	Q3
SN74AUP1G126DCKR	SC70	DCK	5	3000	180.0	9.2	2.24	2.34	1.22	4.0	8.0	Q3
SN74AUP1G126DCKT	SC70	DCK	5	250	180.0	9.2	2.24	2.34	1.22	4.0	8.0	Q3
SN74AUP1G126DRLR	SOT	DRL	5	4000	180.0	9.2	1.78	1.78	0.69	4.0	8.0	Q3
SN74AUP1G126YZPR	DSBGA	YZP	5	3000	180.0	8.4	1.02	1.52	0.63	4.0	8.0	Q1

PACKAGE MATERIALS INFORMATION

www.ti.com 1-Oct-2009



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74AUP1G126DBVR	SOT-23	DBV	5	3000	202.0	201.0	28.0
SN74AUP1G126DBVT	SOT-23	DBV	5	250	202.0	201.0	28.0
SN74AUP1G126DCKR	SC70	DCK	5	3000	202.0	201.0	28.0
SN74AUP1G126DCKT	SC70	DCK	5	250	202.0	201.0	28.0
SN74AUP1G126DRLR	SOT	DRL	5	4000	202.0	201.0	28.0
SN74AUP1G126YZPR	DSBGA	YZP	5	3000	220.0	220.0	34.0

DBV (R-PDSO-G5)

PLASTIC SMALL-OUTLINE PACKAGE



NOTES:

- A. All linear dimensions are in millimeters.
 - B. This drawing is subject to change without notice.
 - C. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.
 - D. Falls within JEDEC MO-178 Variation AA.



DCK (R-PDSO-G5)

PLASTIC SMALL-OUTLINE PACKAGE



NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.
- D. Falls within JEDEC MO-203 variation AA.



DRL (R-PDSO-N5)

PLASTIC SMALL OUTLINE



NOTES:

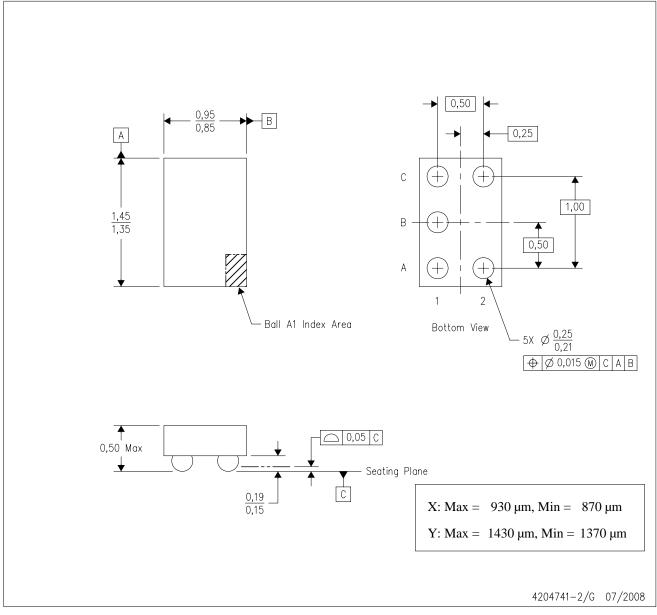
- A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M—1994.
- B. This drawing is subject to change without notice.
- Body dimensions do not include mold flash, interlead flash, protrusions, or gate burrs.

 Mold flash, interlead flash, protrusions, or gate burrs shall not exceed 0,15 per end or side.
- D. JEDEC package registration is pending.



YZP (R-XBGA-N5)

DIE-SIZE BALL GRID ARRAY



NOTES: A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.

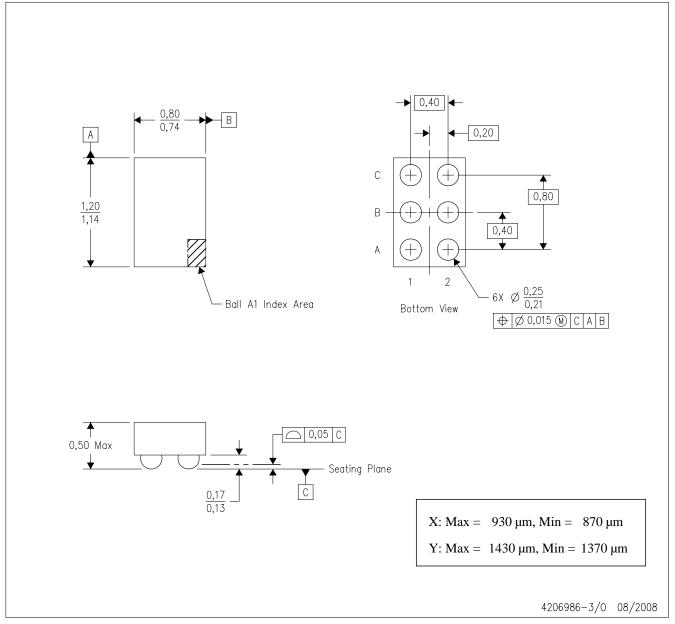
- B. This drawing is subject to change without notice.
- C. NanoFree $^{\text{TM}}$ package configuration.
- D. This package is lead-free. Refer to the 5 YEP package (drawing 4204725) for tin-lead (SnPb).

NanoFree is a trademark of Texas Instruments.



YFP (R-XBGA-N6)

DIE-SIZE BALL GRID ARRAY



NOTES: A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.

- B. This drawing is subject to change without notice.
- C. NanoFree™ package configuration.
- D. This is a Pb-free solder ball design.

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